

# TrenchT4™ **Power MOSFET**

## IXTA380N036T4-7

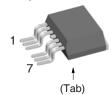
= 36V380A  $\leq 1.0 m\Omega$ 

N-Channel Enhancement Mode Avalanche Rated



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TO-263	(7-lead)



Pins: 1 - Gate 2, 3, 5, 6, 7 - Source 4 (Tab) - Drain

Symbol	Test Conditions	Maximum	Ratings
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 175°C	36	V
V <sub>DGR</sub>	$T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}, R_{gs} = 1\text{M}\Omega$	36	V
V <sub>GSM</sub>	Transient	±15	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	380	Α
LRMS	Lead Current Limit, RMS	160	Α
I <sub>DM</sub>	$T_{_{\rm C}}$ = 25°C, Pulse Width Limited by $T_{_{\rm JM}}$	830	Α
I <sub>A</sub>	T <sub>c</sub> = 25°C	190	А
<b>E</b> <sub>as</sub>	$T_{c} = 25^{\circ}C$	1.4	J
$\mathbf{P}_{D}$	T <sub>c</sub> = 25°C	480	W
T		-55 +175	°C
T <sub>JM</sub>		175	°C
T <sub>stg</sub>		-55 +175	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	g 300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
F <sub>c</sub>	Mounting Force	10.65 / 2.214.6	N/lb
Weight		3.0	g

#### **Features**

- International Standard Package
- 175°C Operating Temperature
- High Current Handling Capability
- Avalanche Rated
- Low R<sub>DS(on)</sub>

### Advantages

- Easy to Mount
- Space Savings
- High Power Density

#### **Applications**

- DC-DC Converts & Off-Line UPS
- High Current Switching Applications
- Primary-Side Switch

			acterist Typ.		
BV <sub>DSS</sub>	$V_{GS} = 0V$ , $I_D = 250\mu A$	36			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250\mu A$	2.0		4.0	V
I <sub>GSS</sub>	$V_{GS} = \pm 15V, V_{DS} = 0V$			±200	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}, V_{GS} = 0V$			10	μА
	T <sub>J</sub> = 150°C			750	μΑ
R <sub>DS(on)</sub>	$V_{GS} = 10V$ , $I_{D} = 100A$ , Note 1			1.0	mΩ



<b>Symbo</b> (T = 25		Test Conditions Unless Otherwise Specified)	Chara Min.	acteristic	Values Max.
g <sub>fs</sub>		$V_{DS} = 10V, I_{D} = 60A, \text{ Note 1}$	105	175	S
$R_{Gi}$		Gate Input Resistance		1.0	Ω
C <sub>iss</sub>	)			13.4	nF
C <sub>oss</sub>	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		2400	pF
$\mathbf{C}_{rss}$	J			1650	pF
t <sub>d(on)</sub>	)	Pariether Quitable a Times		36	ns
t <sub>r</sub>		Resistive Switching Times		78	ns
t <sub>d(off)</sub>		$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 0.5 \cdot I_{D25}$ $R_{G} = 5\Omega$ (External)		125	ns
t <sub>f</sub>	J			80	ns
Q <sub>g(on)</sub>	)			260	nC
Q <sub>gs</sub>	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		60	nC
$\mathbf{Q}_{gd}$	J			92	nC
R <sub>thJC</sub>					0.31 °C/W

#### Source-Drain Diode

SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		cteristic Typ.	Values Max.		
I <sub>s</sub>	$V_{GS} = 0V$			380	Α
I <sub>SM</sub>	Repetitive, Pulse width limited by $\rm T_{_{\rm JM}}$			1520	Α
$V_{SD}$	$I_F = 100A, V_{GS} = 0V, \text{ Note } 1$			1.4	V
t <sub>rr</sub>	$I_{\rm F} = 150 {\rm A},  V_{\rm GS} = 0 {\rm V}$		54		ns
I <sub>RM</sub>	-di/dt = 100A/μs		2.6		Α
$Q_{_{\mathrm{RM}}}$	$V_R = 30V$		70		nC

Note 1: Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

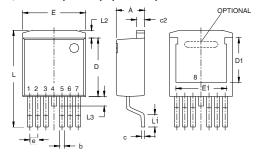
#### **ADVANCE TECHNICAL INFORMATION**

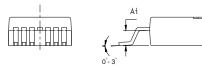
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.



# IXTA380N036T4-7

## TO-263 (7-lead) (IXTA..7) Outline





Pins: 1 - Gate
2, 3, 5 , 6 , 7 - Source
4 - Drain

SYM	INC	HES	MILLIN	METER
2114	MIN	MAX	MIN	MAX
А	.170	.185	4.30	4.70
A 1	.085	.104	2.15	2.65
b	0 9 9	.035	0.65	0.90
С	.016	.024	0.40	0.60
c2	.049	.055	1.25	1.40
D	.355	.370	9.00	9.40
D1	.272	.280	6.90	7.10
E	.386 .386	.402	9.80	10.20
E 1	.311	.319	7.90	8.10
е	.050	BSC	1.27BSC	
L	.591	.614	15.00	15.60
L1	.091	.110	2,30	2.80
L2	.039	.059	1.00	1.50
L3	.000	.059	0.00	1.50

